5-4000 MHz Wideband Low Noise Amplifier



Device Features

- NF = 0.7 dB @ 900MHz at RF connectors of Demo board
- Gain = 19.0 dB @ 900 MHz
- OIP3 = 36.0 dBm @ 1900MHz, 2450MHz
- Output P1 dB = 21.0 dBm @ 900MHz, 22.0 dBm @2450MHz
- 5V/48mA, MTTF > 100 Years, MSL 1, Class 1A
- Lead-free/RoHS-compliant SOT-89 SMT package



Product Description

BeRex's BL051 is a high performance LNA based on GaAs material with E-pHEMT process, packaged in a RoHS-compliant with SOT-89 surface mount package. It is designed for use where low noise and high linearity are required and features low noise and high OIP3 with *low current* at wideband frequency. It requires a few external matching components. All devices are 100% RF/DC tested and classified as HBM ESDS *Class 1A*.

Applications

- Base station Infrastructure/RFID
- Commercial/Industrial/Military wireless system

Typical Performance¹

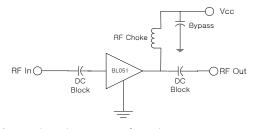
Parameter		Unit				
	900	1900	2140	2450	3500	MHz
Gain	19.0	14.0	13.0	12.0	9.8	dB
S11	-19.5	-22.0	-26.0	-23.5	-18.0	dB
S22	-26.0	-21.0	-17.5	-17.0	-15.0	dB
OIP3 ²	34.5	36.0	36.0	35.5	36.0	dBm
P1dB	21.0	21.5	21.5	22.0	21.0	dBm
Noise Figure	0.70	0.88	0.91	0.94	1.44	dB

Device performance _ measured on a BeRex evaluation board at 25°C, 50 Ω system.

 $^{^{\}rm 2}\,$ OIP3 $_$ measured with two tones at an output of 5 dBm per tone separated by 1 MHz.

	Min.	Typical	Max.	Unit
Bandwidth	5		4000	MHz
I _C @ (Vc = 5V)	38	48	58	mA
V_{C}		5.0		V
R _{TH}		41		°C/W

Applications Circuit



stexternal matching circuit: refer to the page 5 to 13.

Absolute Maximum Ratings

Parameter	Rating	Unit
Operating Case Temperature	-40 to +85	°C
Storage Temperature	-55 to +155	°C
Junction Temperature	+220	°C
Operating Voltage	+6.0	V
Supply Current	200	mA
Input RF Power	30	dBm

Operation of this device above any of these parameters may result in permanent damage.

BeRex

• website: www.berex.com

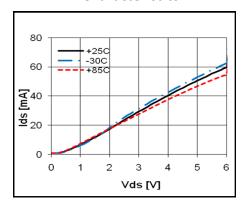
• email: sales@berex.com

1

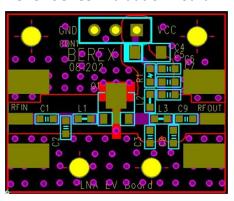
5-4000 MHz Wideband Low Noise Amplifier



V-I Characteristics



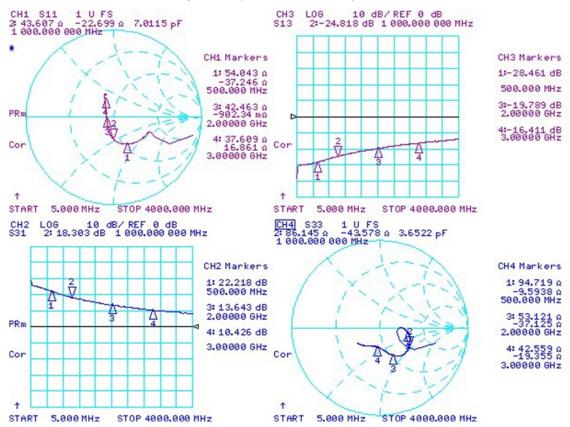
BeRex SOT89 Evaluation Board



*Dielectric constant _ 4.2 *RF pattern width 52mil *31mil thick FR4 PCB

Typical Device Data

S-parameters (Vd=5V, Id=48mA, T=25°C)



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5-4000 MHz Wideband Low Noise Amplifier



S-Parameter

(Vdevice = 5.0V, Icc = 48mA, T = 25 °C, calibrated to device leads)

Freq	S11	S11	S21	S21	S12	S12	S22	S22
[MHz]	[Mag]	[Ang]	[Mag]	[Ang]	[Mag]	[Ang]	[Mag]	[Ang]
100	0.432	-23.546	18.428	162.342	0.032	12.662	0.230	-12.408
500	0.339	-64.094	12.907	122.963	0.038	31.883	0.316	-8.360
1000	0.245	-92.179	8.226	95.114	0.057	43.556	0.396	-32.581
1500	0.153	-112.501	6.008	74.810	0.080	42.095	0.401	-50.839
2000	0.083	-171.662	4.811	58.294	0.102	36.535	0.341	-65.753
2500	0.150	128.339	3.906	44.067	0.125	29.791	0.261	-80.248
3000	0.235	15.431	3.325	31.484	0.152	22.486	0.220	-98.979
3500	0.279	112.352	2.942	20.295	0.174	13.449	0.250	-125.159
4000	0.271	107.520	2.619	7.406	0.270	6.301	0.311	-146.330

Vd = 5V, Id = 48.0mA, Ta = 25° C

Freq	MHz	900	00 1900 2140		2450
S21	dB	19.0	14.0	13.0	12.0
S11	dB	- 19.5	- 22.0	- 26.0	- 23.5
S22	dB	- 26.0	- 21.0	- 17.5	- 17.0
P1	dBm	21.5	21.5	21.6	22.0
OIP3	dBm	34.5	36.0	36.0	35.5
NF	dB	0.70	0.88	0.91	0.94

Vd = 4.8V, Id = 46.0mA, Ta = 25°C

_					
Freq	MHz	900 1900 2		2140	2450
S21	dB	19.0	14.0	13.0	120.
S11	dB	- 19.0	- 21.5	- 22.5	- 23.0
S22	dB	- 27.5	- 22.0	- 18.0	- 17.0
P1	dBm	21.0	21.0	21.5	21.5
OIP3	dBm	34.0	35.8	36.0	35.0
NF	dB	0.71	0.88	0.9	0.94

Vd = 4.6V, Id = 44.0mA, Ta = 25°C

Freq	MHz	900	900 1900 2140		2450
S21	dB	19.0	14.0	13.0	12.0
S11	dB	- 19.0	- 11.0	- 25.0	- 22.5
S22	dB	- 28.5	- 22.5	- 18.5	- 17.5
P1	dBm	20.5	20.5	21.0	21.0
OIP3	dBm	34.0	35.5	35.5	34.5
NF	dB	0.70	0.88	0.89	0.95

Vd = 4.4V, Id = 42.0mA, Ta = 25°C

Freq	MHz	900 1900		2140	2450
S21	dB	18.9	13.9	13.0	11.9
S11	dB	- 18.7	- 20.7	- 24.1	- 22.4
S22	dB	- 29.8	- 23.8	- 19.3	- 17.9
P1	dBm	20.0	20.3	20.7	20.8
OIP3	dBm	33.3	35.0	35.1	34.4
NF	dB	0.70	0.87	0.90	0.93

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5-4000 MHz Wideband Low Noise Amplifier



Vd = 4.2V, Id = 40.0mA, Ta = 25°C

Freq	MHz	900 1900 2140		2450	
S21	dB	19.0	14.0	13.0	12.0
S11	dB	- 18.5	- 20.0	- 23.5	- 21.5
S22	dB	- 28.5	3.5 - 24.5 - 20.0		- 18.5
P1	dBm	19.5	20.0	20.0	20.5
OIP3	dBm	35.0	35.5	34.0	35.0
NF	dB	0.70	0.87	0.90	0.93

Vd = 4.0V, Id = 38.0mA, $Ta = 25^{\circ}C$

Freq	MHz	900	1900	2140	2450
S21	dB	19.0	14.0	13.0	12.5
S11	dB	- 18.5	- 20.0	- 23.0	- 21.0
S22	dB	- 28.0	- 26.0	- 21.0	- 18.5
P1	dBm	19.0	19.5	20.0	20.0
OIP3	dBm	32.5	34.0	34.0	33.4
NF	dB	0.70	0.87	0.89	0.93

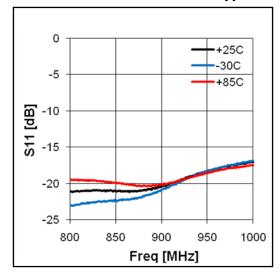
Vd = 3.5V, Id = 33.0mA, Ta = 25° C

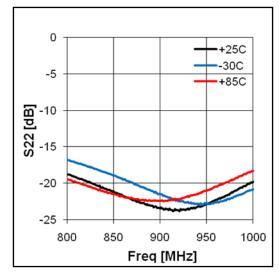
Freq	MHz	900	1900	2140	2450
S21	dB	18.5	13.5	12.5	11.5
S11	dB	- 18.0	- 18.5	- 21.5	- 20.0
S22	dB	- 24.5	- 31.0	- 23.5	- 9.5
P1	dBm	18.5	18.5	19.0	19.0
OIP3	dBm	30.5	32.5	32.5	31.5
NF	dB	0.70	0.86	0.90	0.93



Application Circuit: 900 MHz

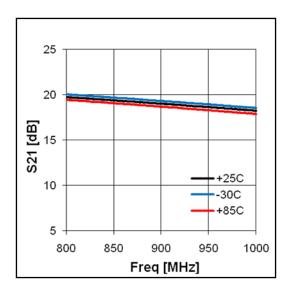
Schematic Diagram		вом	Tolerance
	C1	10uF	± 20%
C3 C2 C1 Vdd	C2	1000pF	± 5%
	С3	100pF	±5%
L2 \	C4	100pF	±5%
BEIN C4 L1 L3 C5 BE Out	C 5	100pF	±5%
RF IN C4 BL051 BL051 BL051	C6	1pF	± 5%
C6 =	L1	3.9nH	±5%
	L2	68nH	±5%
,	L3	6.8nH	±5%

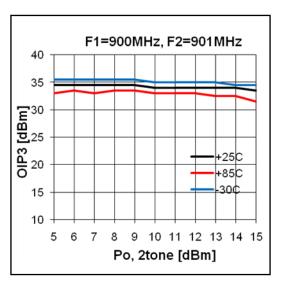


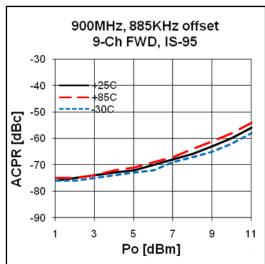


5-4000 MHz Wideband Low Noise Amplifier









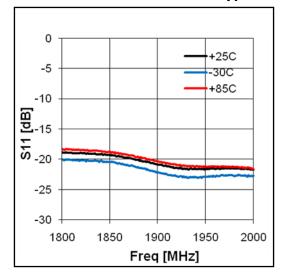
Noise Figure Temperature Performance

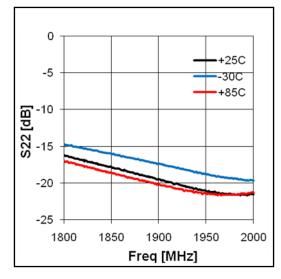
Freq	MHz	900	1900	2140	2450
Ta 100.10	-30	0.65	0.80	0.83	0.87
Temp	25	0.70	0.88	0.91	0.94
[°C]	85	0.83	1.03	1.06	1.10



Application Circuit: 1900 MHz

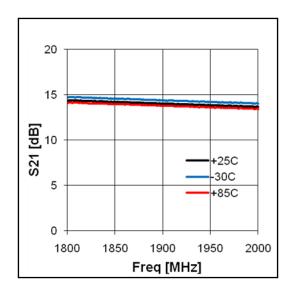
Schematic Diagram		вом	Tolerance
	C1	10uF	± 20%
C3 C2 C1 Vdd	C2	1000pF	± 5%
	C 3	100pF	±5%
	C4	22pF	± 5%
ک پ پ	C 5	22pF	± 5%
RF IN C4 L1 L3 C5 RF Out	C6	0.5pF	± 5%
BL051	С7	0.75pF	±5%
C6 +	L1	1.5nH	±5%
Ţ Ţ	L2	56nH	±5%
	L3	4.7nH	±5%

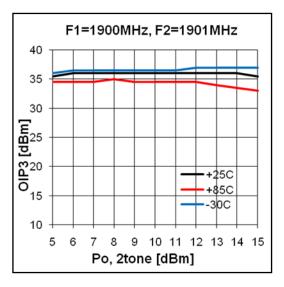


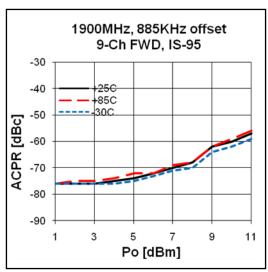


5-4000 MHz Wideband Low Noise Amplifier









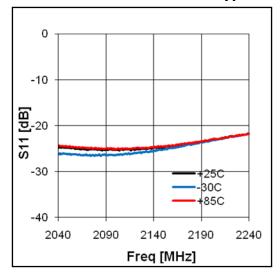
Noise Figure Temperature Performance

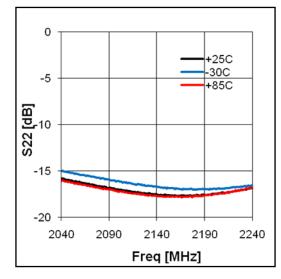
Freq	MHz	900	1900	2140	2450
Toma	-30	0.65	0.80	0.83	0.87
Temp	25	0.70	0.88	0.91	0.94
[°C]	85	0.83	1.03	1.06	1.10



Application Circuit: 2140 MHz

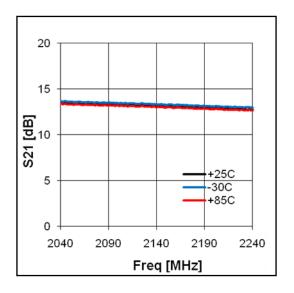
Schematic Diagram		вом	Tolerance
	C1	10uF	± 20%
C3 C2 C1 Vdd	C2	1000pF	± 5%
	С3	100pF	±5%
L2 {	C4	22pF	± 5%
	C 5	22pF	± 5%
RF IN C4 L1 L3 C5 RF Out	C6	0.5pF	± 5%
BL051	C7	0.75pF	±5%
C6 ± C7 ±	L1	1.5nH	±5%
	L2	56nH	±5%
÷ - ÷	L3	3.9nH	±5%

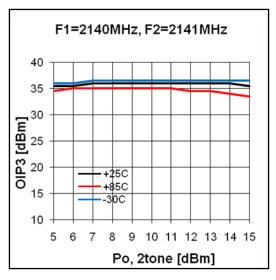


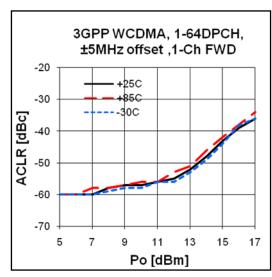


5-4000 MHz Wideband Low Noise Amplifier









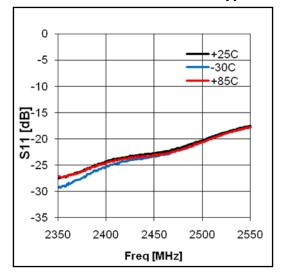
Noise Figure Temperature Performance

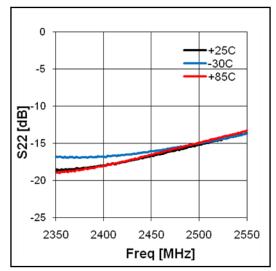
Freq	MHz	900	1900	2140	2450
Toma	-30	0.65	0.80	0.83	0.87
Temp	25	0.70	0.88	0.91	0.94
[°C]	85	0.83	1.03	1.06	1.10



Application Circuit: 2450 MHz

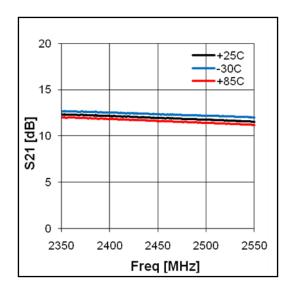
Schematic Diagram		вом	Tolerance
	C1	10uF	± 20%
C3 C2 C1 Vdd	C2	1000pF	± 5%
	C3	100pF	±5%
L2 E	C4	22pF	± 5%
- + + +	C 5	22pF	± 5%
RF IN C4 L1 L3 C5 RF Out	C6	0.5pF	± 5%
BL051	C 7	0.75pF	±5%
C6 + C7 +	L1	1nH	±5%
<u></u>	L2	47nH	±5%
	L3	3.3nH	±5%

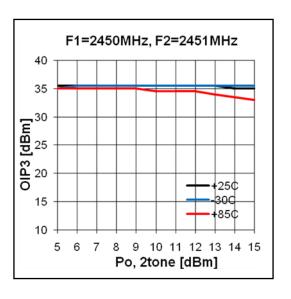


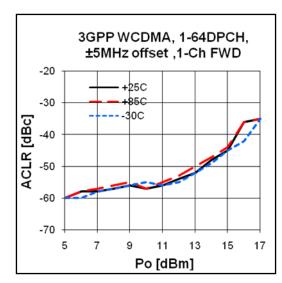


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Noise Figure Temperature Performance

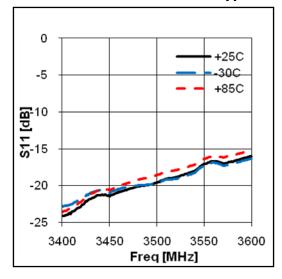
$$(Vds = 5.0V, Ids = 48.0mA)$$

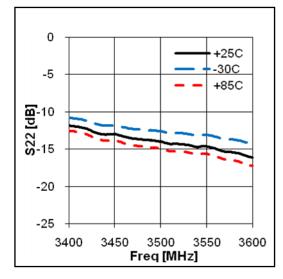
Freq	MHz	900	1900	2140	2450
T	-30	0.65	0.80	0.83	0.87
Temp	25	0.70	0.88	0.91	0.94
[°C]	85	0.83	1.03	1.06	1.10



Application Circuit: 3500 MHz

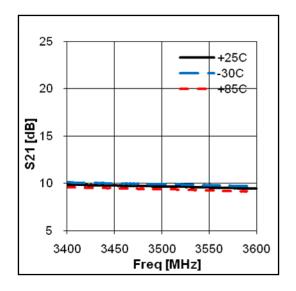
Schematic Diagram		вом	Tolerance
	C1	10uF	± 20%
C3 C2 C1 +5V	C2	1000pF	± 5%
	С3	100pF	±5%
[1] F J J J	C4	18pF	± 5%
<u> </u>	C 5	0.5pF	± 5%
RF IN C4 C6 L2 C8 RF Out	C6	4.7pF	± 5%
BL051	С7	0.5pF	±5%
C5 + C7 +	C8	18pF	±5%
<u> </u>	L1	33nH	±5%
	L2	1.8nH	±5%

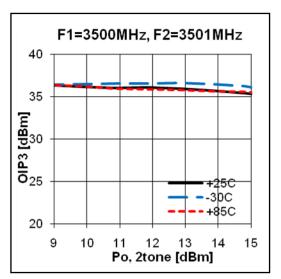




5-4000 MHz Wideband Low Noise Amplifier







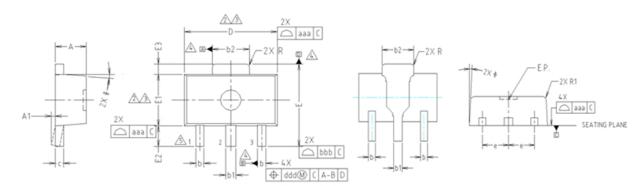
Noise Figure Temperature Performance

Freq	MHz	900	1900	2140	2450	3500
Tomp	-30	0.65	0.80	0.83	0.87	1.32
Temp	25	0.70	0.88	0.91	0.94	1.45
[°C]	85	0.83	1.03	1.06	1.10	1.60

5-4000 MHz Wideband Low Noise Amplifier



Package Outline Dimension



NOTE:

1. DIMENSIONS IN MILLIMETERS.

DIMENSION D DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.

MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 8.5mm PER END.

DIMENSION E1 DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION.

INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 8.5mm PER SIDE.

DIMENSIONS D AND E1 ARE DETERMINED AT THE OUTMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTERLEAD FLASH, BUT INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY.

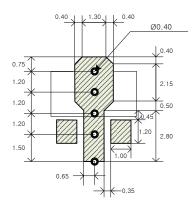
A DATUMS A, B AND D TO BE DETERMINED 8.18mm FROM THE LEAD TIP.

TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.

		MILLI	METERS		NOTE
SYMBOL	MINIMUM	NON	/INAL	MAXIMUM	NOIE
A	1.40	1	.50	1.60	
A1	0.00		_	0.10	
ь	0.38).42	0.48	
ь1	0.48		0.52	0.58	
b2	1.79	1	.82	1.87	
C	0.40	0	.42	0.46	
D E	4.40	4	.50	4.70	2,3
E	3.70	4	.00	4.30	
E1	2.40	2	.50	2.70	2,3
E2	0.80	1	.00	1.20	
E3	0.40	0	.50	0.60	
e		1.5	O TYP.		
0		4	TYP.		
R		0.1	5 TYP.		
R1	_		_	0.20	
SYMBOL	TOLERANCES OF AND POSI	F FORM TION	NOTE		
aaa	0.15	5			
bbb	0.20)			
ccc	0.10)			
ddd	0.10)			

Suggested PCB Land Pattern and PAD Layout

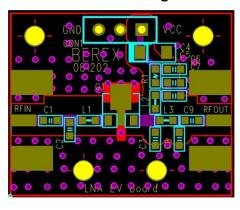
PCB Land Pattern



Note: All dimension _ millimeters

PCB lay out _ on BeRex website

PCB Mounting



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• website: www.berex.com

• email: sales@berex.com

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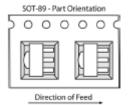
5-4000 MHz Wideband Low Noise Amplifier



Tape & Reel

SOT89

Packaging information:



Tape Width (mm): 12 Reel Size (inches): 7

Device Cavity Pitch (mm): 8

Devices Per Reel: 1000

Lead plating finish

100% Tin Matte finish

(All BeRex products undergoes a 1 hour, 150 degree C, Anneal bake to eliminate thin whisker growth concerns.)

MSL / ESD Rating

ESD Rating: Class 1A

Value: Passes <500V

Test: Human Body Model (HBM)

Standard: JEDEC Standard JESD22-A114B

MSL Rating: Level 1 at +265°C convection reflow

Standard: JEDEC Standard J-STD-020

NATO CAGE code:

2 N 9 6 F
